## The Scattering Matrix

At "low" frequencies, we can completely characterize a linear device or network using an impedance matrix, which relates the currents and voltages at each device terminal to the currents and voltages at all other terminals.

But, at microwave frequencies, it is difficult to measure currents and voltages!


* Instead, we can measure the incident and reflected waves $V_{0}^{+}(z)$ and $V_{0}^{-}(z)$.
* In other words, we can determine the relationship between the incident and reflected wave at each device terminal to the incident and reflected waves at all other terminals.

These relationships are completely represented by the scattering matrix. It completely describes the behavior of a linear, multi-port device at frequency $\omega$.

Consider the 4-port microwave device shown below:


Say we know that there exists an incident wave on port 1 (i.e, $V_{1}^{+} \neq 0$ ), while the incident waves on all other ports are known to be zero (i.e., $V_{2}^{+}=V_{3}^{+}=V_{4}^{+}=0$ ). Say we then measure the wave out of port 2 (i.e., determine $V_{2}^{-}$). The complex ratio between $V_{1}^{+}\left(z=z_{1}\right)$ and $V_{2}^{-}\left(z=z_{2}\right)$ is know as the scattering parameter $\mathrm{S}_{21}:$

$$
S_{21}=\frac{V_{2}^{-}\left(z=z_{2}\right)}{V_{1}^{+}\left(z=z_{1}\right)}=\frac{V_{2}^{-} e^{+j \beta z_{2}}}{V_{1}^{+} e^{-j \beta z_{1}}}=\frac{V_{2}^{-}}{V_{1}^{+}} e^{+j \beta\left(z_{2}+z_{1}\right)}
$$

Likewise, the scattering parameters $S_{31}$ and $S_{41}$ are:

$$
S_{31}=\frac{V_{3}^{-}\left(z=z_{3}\right)}{V_{1}^{+}\left(z=z_{1}\right)} \quad \text { and } \quad S_{41}=\frac{V_{4}^{-}\left(z=z_{4}\right)}{V_{1}^{+}\left(z=z_{1}\right)}
$$

We of course could also define, say, scattering parameter $S_{34}$ as the ratio between the complex values $V_{4}^{+}\left(z=z_{4}\right)$ (describing the wave into port 4) and $V_{3}^{-}\left(z=z_{3}\right)$ (describing the wave out of port 3), given that the input to all other ports (1,2, and 3) are zero.

Thus, more generally, the ratio of the wave incident on port $n$ to the wave emerging from port $m$ is:

$$
S_{m n}=\frac{V_{m}^{-}\left(z=z_{m}\right)}{V_{n}^{+}\left(z=z_{n}\right)} \quad \text { (given that } \quad V_{k}^{+}=0 \text { for all } k \neq n \text { ) }
$$

Note that frequently the port boundary locations are assigned a zero value (e.g., $z_{1}=0, z_{2}=0$ ). This of course simplifies the scattering parameter calculation:

$$
S_{m n}=\frac{V_{m}^{-}\left(z_{m}=0\right)}{V_{n}^{+}\left(z_{n}=0\right)}=\frac{V_{m}^{-} e^{+j \beta 0}}{V_{n}^{+} e^{-j \beta 0}}=\frac{V_{m}^{-}}{V_{n}^{+}}
$$

We will generally assume that the port locations are defined as $z=0$, and thus use the above notation. But remember where this expression came from!

Q: How can we make sure that only one incident wave is non-zero?

A: Terminate all ports with a matched load!


If the ports are terminated in a matched load (i.e., $Z_{L}=Z_{0}$ ), then $\Gamma_{n}=0$ and therefore:

$$
V_{n}^{+}=\Gamma_{n} V_{n}^{-}=0
$$

In other words, terminating a port ensures that there will be no signal incident on that port!

Wait a minute-you've messed this all up! Earlier you said that:

$$
V_{n}^{-}=\Gamma_{n} V_{n}^{+}
$$

but now you say that:

$$
V_{n}^{+}=\Gamma_{n} V_{n}^{-}
$$

Make up your mind! Which one is correct?

Actually, both statements are correct! You must be careful to understand the physical definitions of the constants
$V_{n}^{+}$and $V_{n}^{-}$.

For example, we originally analyzed this case:


In this case, the complex constant describing the wave incident on the load is $V_{n}^{+}$and the constant describing the reflected wave is $V_{n}^{-}$.

Constrast this with the case we are now considering:


Here, we defined the constant of the wave incident on port $n$ as $V_{n}^{+}$. As a result, the constant $V_{n}^{+}$now describes the wave reflected from the load. Likewise, the wave incident on the load is now described by constant $V_{n}^{-}$.

Perhaps we could more generally state that:

$$
V^{\text {reflected }}=\Gamma V^{\text {incident }}
$$

For each case, you must be able to correctly identify the constants describing the wave incident on, and reflected from, some load.

Like most equations in engineering, the variable names can change, but the physics described by the mathematics will not!

Now, back to our discussion of S-parameters. We found that:

$$
V_{m}^{-}=S_{m n} V_{n}^{+} \quad \text { (given that } V_{k}^{+}=0 \text { for all } k \neq n \text { ) }
$$

Which we can now equivalently state as:

$$
V_{m}^{-}=S_{m n} V_{n}^{+} \quad \text { (given that all ports } k \neq n \text { are matched) }
$$

Say that we have waves simultaneously incident on each of the four ports of our device.

Q: What then is the output at, for example, port 3??
A: Use superposition !!

Since the device is linear, the output at port 3 due to all the incident waves is simply the coherent sum of the output at port 3 due to each wave:

$$
V_{3}^{-}=S_{34} V_{4}^{+}+S_{33} V_{3}^{+}+S_{32} V_{2}^{+}+S_{31} V_{1}^{+}
$$

Or, more generally, the output at port $m$ of an $N$-port device is:

$$
V_{m}^{-}=\sum_{n=1}^{N} S_{m n} V_{n}^{+}
$$

This expression can be written in matrix form as:

$$
\overline{\mathbf{V}}^{-}=\overline{\overline{\mathbf{S}}} \overline{\mathbf{V}}^{+}
$$

Where $\overline{\mathbf{V}}^{-}$is the vector:

$$
\overline{\mathbf{V}}^{-}=\left[\boldsymbol{V}_{1}^{-}, \boldsymbol{V}_{2}^{-}, \boldsymbol{V}_{3}^{-}, \ldots, \boldsymbol{V}_{N}^{-}\right]^{\top}
$$

and $\overline{\mathbf{V}}^{+}$is the vector:

$$
\overline{\mathbf{V}}^{+}=\left[\boldsymbol{V}_{1}^{+}, \boldsymbol{V}_{2}^{+}, \boldsymbol{V}_{3}^{+}, \ldots, \boldsymbol{V}_{N}^{+}\right]^{\top}
$$

Therefore $\overline{\overline{\mathbf{S}}}$ is the scattering matrix:

$$
\overline{\overline{\mathbf{S}}}=\left(\begin{array}{ccc}
S_{11} & \cdots & S_{1 n} \\
\vdots & \ddots & \vdots \\
S_{m 1} & \cdots & S_{m n}
\end{array}\right)
$$

The scattering matrix is a Nbs $N$ matrix that completely characterizes a linear, $N$-port device (at frequency $\omega$ ).

